



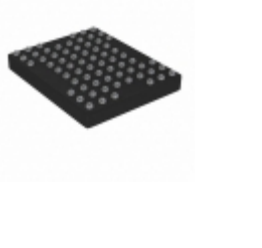
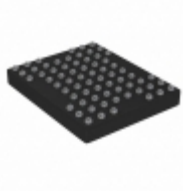



 <p><b>TOSHIBA</b> Leading Innovation &gt;&gt;&gt;</p>	<h2 style="color: red;">TC58NVG2S0HTAI0</h2>	
	<p><b>Hersteller-Teilenummer:</b> <a href="#">TC58NVG2S0HTAI0</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Toshiba Semiconductor and Storage</a></p> <hr/> <p><b>Teil der Beschreibung:</b> IC EEPROM 4GBIT 25NS 48TSOP</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">TC58NVG2S0HTAI0.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 9600 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	TC58NVG2S0HTAI0
Hersteller	Toshiba Semiconductor and Storage
Beschreibung	IC EEPROM 4GBIT 25NS 48TSOP
Kategorie	<a href="#">Integrierte Schaltungen (ICs) &gt; Erinnerung</a>
Teilstatus	9600 pcs Stock
Serie	-
Betriebstemperatur	-40°C ~ 85°C (TA)
Schnittstelle	Parallel
Verpackung / Gehäuse	48-TFSOP (0.724", 18.40mm Width)
Supplier Device-Gehäuse	48-TSOP I
Spannungsversorgung	2.7 V ~ 3.6 V
Speichertyp	Non-Volatile
Geschwindigkeit	25ns
Speichergröße	4Gb (512M x 8)
Speicherformat	EEPROM
Verpackung	Tray

TC58NVG2S0HTAI0 ist neu im Original, Suche TC58NVG2S0HTAI0 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie TC58NVG2S0HTAI0 Toshiba Semiconductor and Storage mit Garantie und Vertrauen. Anfrage TC58NVG2S0HTAI0: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>TC58NVG2S3ETA00</b> TOSHIBA TC58NVG2S3ETA00 TOSHIBA</p>	 <p><b>TC58NVG2S3ETAOCB3H</b> TOSHIBA TC58NVG2S3ETAOCB3H TOSHIBA</p>	 <p><b>TC58NVG2S5HBAI6</b> Toshiba Semiconductor and Storage TC58NVG2S5HBAI6 TOSHIBA</p>	 <p><b>TC58NVG2S0HBAI6</b> Toshiba Semiconductor and Storage IC EEPROM 4GBIT 25NS 67FBGA</p>
 <p><b>TC58NVG2S0HBAI6</b> Toshiba Memory America, Inc. IC FLASH 4G PARALLEL 67VFBGA</p>	 <p><b>TC58NVG2S0HTA00</b> Toshiba Semiconductor and Storage IC EEPROM 4GBIT 25NS 48TSOP</p>	 <p><b>TC58NVG2S0HTA00</b> Toshiba Memory America, Inc. IC FLASH 4G PARALLEL 48TSOP I</p>	 <p><b>TC58NVG2S0HTAI0</b> Toshiba Memory America, Inc. IC FLASH 4G PARALLEL 48TSOP I</p>

### heiße Teile

Mehr

 TC58NVG0S3AFT05	 TC58NVG0S3EBAI4	 TC58NVG0S3EBAI7	 TC58NVG0S3EBAI7LRH	 TC58NVG0S3ETA00
 TC58NVG0S3ETA10	 TC58NVG0S3ETA10	 TC58NVG0S3HBAI6	 TC58NVG0S3HBAI6	 TC58NVG0S3HTAI0
 TC58NVG0S3HTAI0	 TC58NVG0S3HTAI0B4H	 TC58NVG1S3EBAI4	 TC58NVG1S3EBAI5	 TC58NVG1S3ETA00
 TC58NVG1S3ETA00	 TC58NVG1S3ETA10	 TC58NVG1S3ETA10	 TC58NVG1S3ETA10	 TC58NVG1S3HBAI4
 TC58NVG1S3HBAI4	 TC58NVG1S3HBAI6	 TC58NVG1S3HBAI6	 TC58NVG1S3HTA00	 TC58NVG1S3HTA00
 TC58NVG2S0HTAI0	 TC58NVG2S3ETA00	 TC58NVG2S5HBAI6	 TC58NVG3S0FTA00B4H	 TC58NVG4D2ETA100
 TC58NYG1S8HBAI6	 TC58NYG2S3ETA10	 TC58NYG2S3ETA10	 TC58NYM9S3EBAI4	 TC58RYG0S8EBAIA
 TC58RYG0S8EBAIB	 TC58RYG1S8EBAIA	 TC58TEG5DCJTA00	 TC58V16BFT	 TC58V64BFT
 TC593002ECBTR	 TC59LM806CTG-50	 TC59LM814CTG-50	 TC59LM818DKBI37	 TC59S1616AFT-10
 TC59S6416BFTL10	 TC59S6416CFT-80	 TC59S6432CFT70	 TC59S6432DFT-70	 TC59SM716T80

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